

MANUFACTURER DOCUMENT PACKAGE

Manufacturer's Manual

Reference package for procurement and maintenance review

INFINEON

TD330N16KOF

PHASE CONTROL THYRISTOR/DIODE MODULE

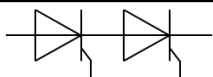
Used with the applicable Infineon Power Block modules configuration.

REFERENCE PACKAGE

OFFICIAL DOCUMENT

Selected official manufacturer pages follow this cover.

Source: Infineon official manufacturer documentation



Technische Information / technical information



Netz-Thyristor-Modul
Phase Control Thyristor Module

TT330N

Infineon Technologies Bipolar
GmbH & Co. KG

Key Parameters

$V_{\text{DRM}} / V_{\text{RRM}}$	1600V
I_{TAVM}	330A ($T_c=85^\circ\text{C}$)
I_{TSM}	12500A
V_{T0}	0,8V
r_{T}	0,5m Ω
R_{thJC}	0,106K/W
Base plate	50mm



For type designation please refer to actual
short form catalog

<http://www.ifbip.com/catalog>

Merkmale

- Druckkontakt-Technologie für hohe Zuverlässigkeit
- Advanced Medium Power Technology (AMPT)
- Industrie-Standard-Gehäuse
- Elektrisch isolierte Bodenplatte
- Optional: Thermisches Interface Material (TIM) bereits aufgetragen

Features

- Pressure contact technology for high reliability
- Advanced Medium Power Technology (AMPT)
- Industrial standard package
- Electrically insulated base plate
- Option: Pre-applied thermal interface material (TIM)

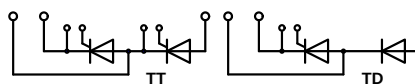
Typische Anwendungen

- Sanftanlasser
- Gleichrichter für Antriebsapplikationen
- Kurzschließer-Applikationen
- Leistungssteller
- Gleichrichter für UPS
- Batterieladegleichrichter
- Statische Umschalter

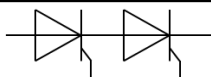
Typical Applications

- Soft starter
- Rectifier for drives applications
- Crowbar applications
- Power controllers
- Rectifiers for UBS
- Battery chargers
- Static switches

content of customer DMX code	DMX code digit	DMX code digit quantity
serial number	1..5	5
SAP material number	6..12	7
Internal production order number	13..20	8
datecode (production year)	21..22	2
datecode (production week)	23..24	2



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TT330N16KOF_TIM

TD330N16KOF_TIM

Elektrische Eigenschaften / Electrical properties

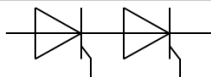
Höchstzulässige Werte / Maximum rated values

Periodische Vorwärts- und Rückwärts-Spitzensperrspannung repetitive peak forward off-state and reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj \max}$	$V_{\text{DRM}}, V_{\text{RRM}}$	1200	1400 1600	V V
Vorwärts-Stoßspitzensperrspannung non-repetitive peak forward off-state voltage	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj \max}$	V_{DSM}	1200	1400 1600	V V
Rückwärts-Stoßspitzensperrspannung non-repetitive peak reverse voltage	$T_{vj} = +25^{\circ}\text{C} \dots T_{vj \max}$	V_{RSM}	1300	1500 1700	V V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		I_{TRMSM}		520	A
Dauergrenzstrom average on-state current	$T_c = 85^{\circ}\text{C}$	I_{TAVM}		330	A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj \max}, t_p = 10\text{ms}$	I_{TSM}		12500 10000	A A
Grenzlastintegral I^2t -value	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj \max}, t_p = 10\text{ms}$	I^2t		781250 500000	A ² s A ² s
Kritische Stromsteilheit critical rate of rise of on-state current	DIN IEC 747-6 $f = 50\text{Hz}, i_{\text{GM}} = 1\text{A}, di_G/dt = 1\text{A}/\mu\text{s}$	$(di_T/dt)_{\text{cr}}$		250	A/ μs
Kritische Spannungssteilheit critical rate of rise of off-state voltage	$T_{vj} = T_{vj \max}, V_D = 0,67 V_{\text{DRM}}$ 6.Kennbuchstabe / 6 th letter F	$(dv_D/dt)_{\text{cr}}$		1000	V/ μs

Charakteristische Werte / Characteristic values

Durchlaßspannung on-state voltage	$T_{vj} = T_{vj \max}, i_T = 800\text{A}$	v_T	max.	1,28	V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj \max}$	$V_{(\text{TO})}$	max.	0,8	V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj \max}$	r_T	max.	0,5	m Ω
Zündstrom gate trigger current	$T_{vj} = 25^{\circ}\text{C}, V_D = 12\text{V}$	I_{GT}	max.	200	mA
Zündspannung gate trigger voltage	$T_{vj} = 25^{\circ}\text{C}, V_D = 12\text{V}$	V_{GT}	max.	2	V
Nicht zündender Steuerstrom gate non-trigger current	$T_{vj} = T_{vj \max}, V_D = 12\text{V}$ $T_{vj} = T_{vj \max}, V_D = 0,5 V_{\text{DRM}}$	I_{GD}	max. max.	10 5	mA mA
Nicht zündende Steuerspannung gate non-trigger voltage	$T_{vj} = T_{vj \max}, V_D = 0,5 V_{\text{DRM}}$	V_{GD}	max.	0,2	V
Haltestrom holding current	$T_{vj} = 25^{\circ}\text{C}, V_D = 12\text{V}, R_A = 1\Omega$	I_{H}	max.	300	mA
Einraststrom latching current	$T_{vj} = 25^{\circ}\text{C}, V_D = 12\text{V}, R_{\text{GK}} \geq 10\Omega$ $i_{\text{GM}} = 1\text{A}, di_G/dt = 1\text{A}/\mu\text{s}, t_g = 20\mu\text{s}$	I_{L}	max.	1200	mA
Vorwärts- und Rückwärts-Sperrstrom forward off-state and reverse current	$T_{vj} = T_{vj \max}$ $V_D = V_{\text{DRM}}, V_R = V_{\text{RRM}}$	i_D, i_R	max.	70	mA
Zündverzögerung gate controlled delay time	DIN IEC 747-6 $T_{vj} = 25^{\circ}\text{C}, i_{\text{GM}} = 1\text{A}, di_G/dt = 1\text{A}/\mu\text{s}$	t_{gd}	max.	3	μs

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Elektrische Eigenschaften / Electrical properties

Charakteristische Werte / Characteristic values

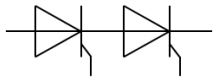
Freiwerdezeit circuit commutated turn-off time	$T_{vj} = T_{vj\max}, i_{TM} = I_{TAVM}$ $V_{RM} = 100\text{ V}, V_{DM} = 0,67 V_{DRM}$ $dv_D/dt = 20\text{ V}/\mu\text{s}, -di_T/dt = 10\text{ A}/\mu\text{s}$ 5. Kennbuchstabe / 5 th letter O	t_q	typ.	250	μs
Isolations-Prüfspannung insulation test voltage	RMS, $f = 50\text{ Hz}, t = 1\text{ min}$ RMS, $f = 50\text{ Hz}, t = 1\text{ sec}$	V_{ISOL}		3,0 3,6	kV kV

Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resistance, junction to case	pro Modul / per Module, $\Theta = 180^\circ \sin$ pro Zweig / per arm, $\Theta = 180^\circ \sin$ pro Modul / per Module, DC pro Zweig / per arm, DC	R_{thJC}	max.	0,056	K/W
			max.	0,112	K/W
			max.	0,053	K/W
			max.	0,106	K/W
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	pro Modul / per Module pro Zweig / per arm	R_{thCH}	max.	0,02	K/W
			max.	0,04	K/W
Übergangs-Wärmewiderstand mit TIM thermal resistance, case to heatsink, with TIM	pro Modul / per Module pro Zweig / per arm		max.	0,015	K/W
			max.	0,030	K/W
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\max}$		130	$^\circ\text{C}$
Betriebstemperatur operating temperature		$T_{c\text{ op}}$		-40...+130	$^\circ\text{C}$
Lagertemperatur storage temperature		T_{stg}		-40...+130	$^\circ\text{C}$
Lagertemperatur mit TIM storage temperature with TIM				+5...+50	$^\circ\text{C}$

Mechanische Eigenschaften / Mechanical properties

Gehäuse, siehe Anlage case, see annex				Seite 4 page 4	
Si-Element mit Druckkontakt Si-pellet with pressure contact					
Innere Isolation internal insulation	Basisisolation (Schutzklasse 1, EN61140) Basic insulation (class 1, IEC61140)			AIN	
Anzugsdrehmoment für mechanische Anschlüsse mounting torque	Toleranz / Tolerance $\pm 15\%$	M1		5	Nm
Anzugsdrehmoment für elektrische Anschlüsse terminal connection torque	Toleranz / Tolerance $\pm 10\%$	M2		12	Nm
Steueranschlüsse control terminals	DIN 46 244			A 2,8 x 0,8	
Gewicht weight		G	typ.	800	g
Kriechstrecke creepage distance				17	mm
Schwingfestigkeit vibration resistance	$f = 50\text{ Hz}$			50	m/s^2
	file-No.			E 83335	



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